# imall

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#### **Product Summary**

V <sub>(BR)DSS</sub>	R <sub>DS(ON)</sub> max	I <sub>D</sub> max T <sub>A</sub> = +25°C
	80mΩ @ V <sub>GS</sub> = 10V	4.1A
60V	100mΩ @ V <sub>GS</sub> = 4.5V	3.6A

### **Description and Applications**

This MOSFET is designed to minimize the on-state resistance  $(R_{DS(on)})$  and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

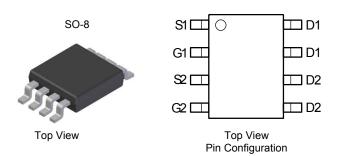
- Backlighting
- Power Management Functions
- DC-DC Converters

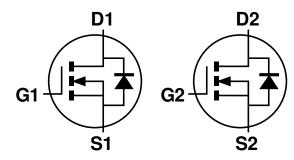
### **Features and Benefits**

- Low On-Resistance
- Low Input Capacitance
- Fast Switching Speed
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

#### Mechanical Data

- Case: SO-8
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections Indicator: See Diagram
- Terminals: Finish Matte Tin Annealed over Copper Leadframe Solderable per MIL-STD-202, Method 208
- Weight: 0.074 grams (Approximate)





Equivalent Circuit

#### Ordering Information (Note 4)

Part Number	Case	Packaging
DMN6070SSD-13	SO-8	2,500/Tape & Reel

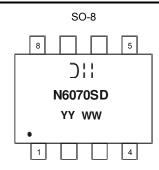
Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

#### **Marking Information**



) | | = Manufacturer's Marking N6070SD = Product Type Marking Code YYWW = Date Code Marking YY = Year (ex: 13 = 2013) WW = Week (01 - 53)



#### Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic Drain-Source Voltage Gate-Source Voltage			Symbol	Value	Units V	
			V <sub>DSS</sub>	60		
			V <sub>GSS</sub>	±20	V	
	Steady State	T <sub>A</sub> = +25°C T <sub>A</sub> = +70°C	ID	3.3 2.6	А	
Continuous Drain Current (Note 6) V <sub>GS</sub> = 10V	t<10s	T <sub>A</sub> = +25°C T <sub>A</sub> = +70°C	Ι <sub>D</sub>	4.1 3.4	А	
Maximum Continuous Body Diode Forward Current (Note 5)			Is	2.0	А	
Pulsed Drain Current (10µs pulse, duty cycle = 1%)			I <sub>DM</sub>	12	A	
Avalanche Current (Note 7) L=0.1mH			I <sub>AS</sub>	10	А	
Avalanche Energy (Note 7) L=0.1mH			E <sub>AS</sub>	5.9	mJ	

#### Thermal Characteristics (@T<sub>A</sub>= +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Units		
Total Power Dissipation (Note 5)		PD	1.2	W	
Thermal Desistance Junction to Ambient (Note E)	Steady State	D	104	°C/W	
Thermal Resistance, Junction to Ambient (Note 5)	t<10s	$R_{ extsf{ heta}JA}$	61	C/W	
Total Power Dissipation (Note 6)		PD	1.5	W	
Thermal Desistance, Junction to Ambient (Note 6)	Steady State		83	°C/W	
Thermal Resistance, Junction to Ambient (Note 6)	t<10s	R <sub>θ</sub> JA	50		
Thermal Resistance, Junction to Case	$R_{\theta JC}$	14.5			
Operating and Storage Temperature Range		TJ. TSTG	-55 to +150	°C	

#### Electrical Characteristics (@TA= +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 8)	Cymbol		- YP	max	Onit		
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	60	—	_	V	I <sub>D</sub> = 250μA, V <sub>GS</sub> = 0V	
Zero Gate Voltage Drain Current	IDSS	_	_	1	μA	V <sub>DS</sub> = 60V, V <sub>GS</sub> = 0V	
Gate-Source Leakage	I <sub>GSS</sub>	_	_	±100	nA	V <sub>GS</sub> = ±16V, V <sub>DS</sub> = 0V	
ON CHARACTERISTICS (Note 8)							
Gate Threshold Voltage	V <sub>GS(th)</sub>	1.0	_	3.0	V	I <sub>D</sub> = 250μA, V <sub>DS</sub> = V <sub>GS</sub>	
Static Drain-Source On-Resistance			68	80	mΩ	V <sub>GS</sub> = 10V, I <sub>D</sub> = 4.5A	
Static Drain-Source On-Resistance	Rds (ON)	_	70	100		V <sub>GS</sub> = 4.5V, I <sub>D</sub> = 3.5A	
Diode Forward Voltage	V <sub>SD</sub>	_	0.75	1.1	V	I <sub>S</sub> = 12A, V <sub>GS</sub> = 0V	
DYNAMIC CHARACTERISTICS (Note 9)							
Input Capacitance	C <sub>iss</sub>	_	588	_		V <sub>DS</sub> = 30V, V <sub>GS</sub> = 0V f= 1MHz	
Output Capacitance	C <sub>oss</sub>	_	26.5		pF		
Reverse Transfer Capacitance	Crss	_	20	—			
Gate Resistance	R <sub>g</sub>	_	1.5	_	Ω	Vgs= 0V, Vds= 0V, f=1MHz,	
Total Gate Charge (V <sub>GS</sub> = 4.5V)	Qg	_	5.6	_			
Total Gate Charge (V <sub>GS</sub> = 10V)	Qg	_	12.3	_	nC	V <sub>DS</sub> = 30V, I <sub>D</sub> = 3A	
Gate-Source Charge	Q <sub>gs</sub>	_	1.7	_	nc		
Gate-Drain Charge	Q <sub>gd</sub>	_	1.9	_			
Turn-On Delay Time	t <sub>D(on)</sub>	_	3.5	_			
Turn-On Rise Time	tr	_	4.1	_	-0	$\label{eq:VDD} \begin{array}{l} V_{DD}\text{=} \; 30\text{V}, \; V_{GS}\text{=} \; 10\text{V} \\ R_L \cong 50\Omega, \; R_G \cong 20\Omega \end{array}$	
Turn-Off Delay Time	t <sub>D(off)</sub>		35	_	nS		
Turn-Off Fall Time	t <sub>f</sub>		11	_			
Body Diode Reverse Recovery Time	trr	_	18	_	nS	I <sub>S</sub> = 12A, dI/dt = 100A/µs	
Body Diode Reverse Recovery Charge	Qrr	_	12	_	nC	I <sub>S</sub> = 12A, dl/dt = 100A/µs	

5. Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.
6. Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate.
7. I<sub>AS</sub> and E<sub>AS</sub> rating are based on low frequency and duty cycles to keep T<sub>J</sub> = +25°C.
8. Short duration pulse test used to minimize self-heating effect.
9. Guaranteed by design. Not subject to product testing. Notes:



4.5 5

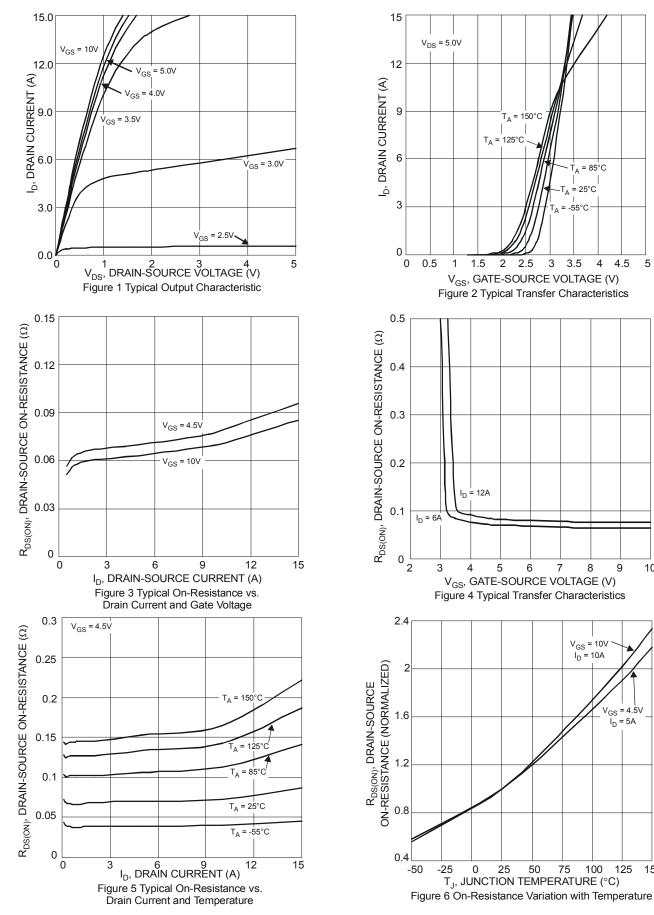
9

= 4.5V

= 5A

125

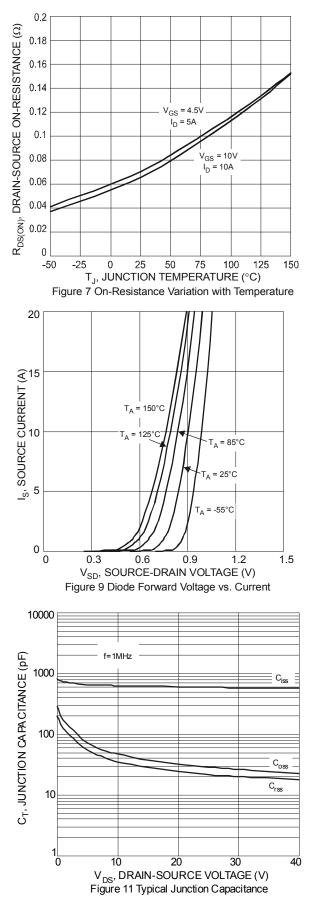
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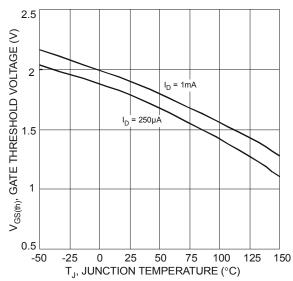


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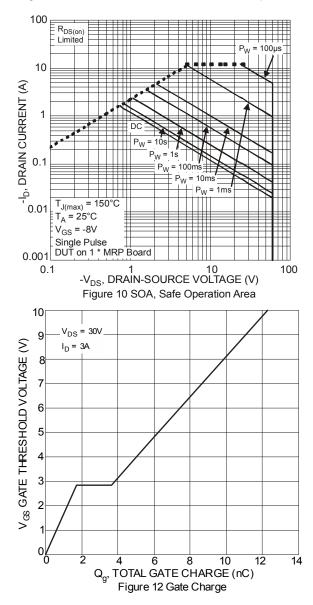




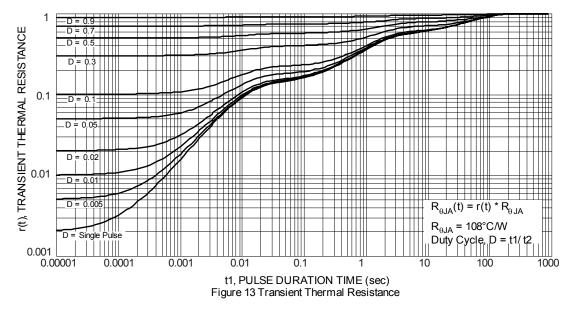






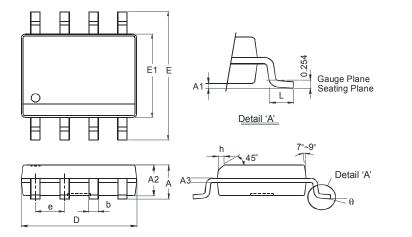






## **Package Outline Dimensions**

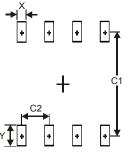
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



SO-8					
Dim	Min	Max			
Α	-	1.75			
A1	0.10	0.20			
A2	1.30	1.50			
A3	0.15	0.25			
b	0.3	0.5			
D	4.85	4.95			
ш	5.90	6.10			
E1	3.85 3.95				
e	е 1.27 Тур				
h	- 0.35				
L	0.62	0.82			
θ	0°	8°			
All Di	All Dimensions in mm				

### **Suggested Pad Layout**

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
Х	0.60
Y	1.55
C1	5.4
C2	1.27

DMN6070SSD Document number: DS36342 Rev. 3 - 2



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